









TLV387, TLV2387, TLV4387 SBOSA91B - DECEMBER 2021 - REVISED DECEMBER 2023

# TLVx387 High Precision, Zero-Drift, Low-Input-Bias-Current Op Amps

#### 1 Features

- Ultra-low offset voltage: ±10 µV (maximum)
- Zero drift: ±0.01 µV/°C
- Low-input bias current: 300 pA (maximum)
- Low noise: 8.5 nV/√Hz at 1 kHz
- No 1/f noise: 177  $nV_{PP}$  (0.1 Hz to 10 Hz)
- Common-mode input range ±100 mV beyond supply rails
- Gain bandwidth: 5.7 MHz
- Quiescent current: 570 µA per amplifier
- Single supply: 1.7 V to 5.5 V Dual supply: ±0.85 V to ±2.75 V
- EMI and RFI filtered inputs

# 2 Applications

- Electronic thermometer
- Weigh scale
- Temperature transmitter
- Ventilators
- Data acquisition (DAQ)
- Semiconductor test
- Lab and field instrumentation
- Merchant network and server PSU
- Analog input module
- Pressure transmitter

## 3 Description

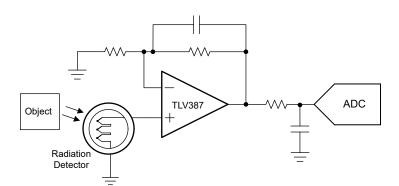
The TLV387, TLV2387, and TLV4387 (TLVx387) family of precision amplifiers offers state-of-the-art performance. With zero-drift technology, the TLVx387 offset voltage and offset drift provide unparalleled long-term stability. With a mere 570 µA of quiescent current, the TLVx387 are able to achieve 5.7 MHz of bandwidth, a broadband noise of 8.5 nV/ $\sqrt{Hz}$ , and a 1/f noise at 177 nV<sub>PP</sub>. These specifications are crucial to achieve extremely-high precision and no degradation of linearity in 16-bit to 24-bit analog to digital converters (ADCs). The TLVx387 feature flat bias current over temperature; therefore, little to no calibration is needed in high input impedance applications over temperature.

All versions are specified over the temperature range of -40°C to +125°C.

#### **Device Information**

| PART NUMBER | CHANNEL COUNT | PACKAGE <sup>(1)</sup> |  |  |  |
|-------------|---------------|------------------------|--|--|--|
| TLV387      | Single        | DBV (SOT-23, 5)        |  |  |  |
| TLV2387     | Dual          | D (SOIC, 8)            |  |  |  |
| 1LV2307     | Duai          | DGK (VSSOP, 8)         |  |  |  |
| TLV4387     | Quad          | PW (TSSOP, 14)         |  |  |  |

For more information, see Section 10.



The TLV387 as a Precision, Low-Noise ADC Driver



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# **4 Pin Configuration and Functions**

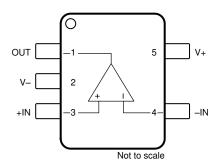


Figure 4-1. TLV387: DBV Package, 5-Pin SOT-23 (Top View)

Table 4-1. Pin Functions: TLV387

| P    | IN  | TYPE   | DESCRIPTION                     |  |
|------|-----|--------|---------------------------------|--|
| NAME | NO. | 1175   | DESCRIPTION                     |  |
| -IN  | 3   | Input  | Inverting input                 |  |
| +IN  | 4   | Input  | Noninverting input              |  |
| OUT  | 6   | Output | Output                          |  |
| V-   | 5   | Power  | Negative (lowest) power supply  |  |
| V+   | 1   | Power  | Positive (highest) power supply |  |

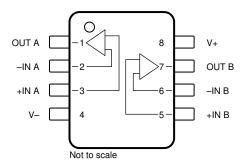


Figure 4-2. TLV2387: D Package, 8-Pin SOIC and DGK Package, 8-Pin VSSOP (Top View)

Table 4-2. Pin Functions: TLV2387

|             | PIN                      |             |        |                                 |
|-------------|--------------------------|-------------|--------|---------------------------------|
|             | N                        | 0.          | TYPE   | DESCRIPTION                     |
| NAME        | D (SOIC), DGK<br>(VSSOP) | DSG (WSON)  |        |                                 |
| −IN A       | 2                        | 2           | Input  | Inverting input, channel A      |
| –IN B       | 6                        | 6           | Input  | Inverting input, channel B      |
| +IN A       | 3                        | 3           | Input  | Noninverting input, channel A   |
| +IN B       | 5                        | 5           | Input  | Noninverting input, channel B   |
| OUT A       | 1                        | 1           | Output | Output, channel A               |
| OUT B       | 7                        | 7           | Output | Output, channel B               |
| V-          | 4                        | 4           | Power  | Negative (lowest) power supply  |
| V+          | 8                        | 8           | Power  | Positive (highest) power supply |
| Thermal Pad | _                        | Thermal pad | _      | Connect thermal pad to V-       |



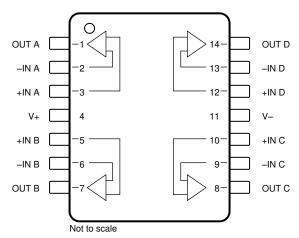


Figure 4-3. TLV4387: PW Package, 14-Pin TSSOP (Top View)

Table 4-3. Pin Functions: TLV4387

|       | Table 4-5. I III I diletions. TEV4507 |        |                                 |  |  |  |
|-------|---------------------------------------|--------|---------------------------------|--|--|--|
| F     | PIN                                   | TYPE   | DESCRIPTION                     |  |  |  |
| NAME  | NO.                                   | 1117   | DESCRIPTION                     |  |  |  |
| –IN A | 2                                     | Input  | Inverting input, channel A      |  |  |  |
| –IN B | 6                                     | Input  | Inverting input, channel B      |  |  |  |
| –IN C | 9                                     | Input  | Inverting input, channel C      |  |  |  |
| –IN D | 13                                    | Input  | Inverting input, channel D      |  |  |  |
| +IN A | 3                                     | Input  | Noninverting input, channel A   |  |  |  |
| +IN B | 5                                     | Input  | Noninverting input, channel B   |  |  |  |
| +IN C | 10                                    | Input  | Noninverting input, channel C   |  |  |  |
| +IN D | 12                                    | Input  | Noninverting input, channel D   |  |  |  |
| OUT A | 1                                     | Output | Output, channel A               |  |  |  |
| OUT B | 7                                     | Output | Output, channel B               |  |  |  |
| OUT C | 8                                     | Output | Output, channel C               |  |  |  |
| OUT D | 14                                    | Output | Output, channel D               |  |  |  |
| V-    | 11                                    | Power  | Negative (lowest) power supply  |  |  |  |
| V+    | 4                                     | Power  | Positive (highest) power supply |  |  |  |

Product Folder Links: TLV387 TLV2387 TLV4387



# **5 Specifications**

# 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

|                  | 1 5 1 5                             |               | MIN        | MAX               | UNIT |  |
|------------------|-------------------------------------|---------------|------------|-------------------|------|--|
| \/               | Supply Voltage V = (V+) (V)         | Single-supply |            | 6                 | V    |  |
| Vs               | Supply Voltage, $V_S = (V+) - (V-)$ | Dual-supply   |            | ±3                | V    |  |
|                  | Input voltage all pine              | Common-mode   | (V-) - 0.5 | (V+) + 0.5        | V    |  |
|                  | Input voltage, all pins             | Differential  |            | (V+) - (V-) + 0.2 | V    |  |
|                  | Input current, all pins             |               |            | ±10               | mA   |  |
|                  | Output short circuit <sup>(2)</sup> |               | Continuous | Continuous        |      |  |
| T <sub>A</sub>   | Operating temperature               |               | -55        | 150               | °C   |  |
| TJ               | Junction temperature                |               | -55        | 150               | °C   |  |
| T <sub>stg</sub> | Storage temperature                 |               | -65        | 150               | °C   |  |

<sup>(1)</sup> Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

## 5.2 ESD Ratings

|    |                    |                         |   | VALUE | UNIT |
|----|--------------------|-------------------------|---|-------|------|
| Ι, |                    | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>     | ±3000 | V    |
|    | V <sub>(ESD)</sub> |                         | Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup> | ±1000 | ·    |

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

## **5.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

|                |                                     |               | MIN   | NOM MAX | UNIT |
|----------------|-------------------------------------|---------------|-------|---------|------|
| V.             | Supply voltage, $V_S = (V+) - (V-)$ | Single-supply | 1.7   | 5.5     | V    |
| Vs             | Supply voltage, $v_S = (v+) = (v-)$ | Dual-supply   | ±0.85 | ±2.75   | V    |
| T <sub>A</sub> | Specified temperature               |               | -40   | 125     | °C   |

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<sup>(2)</sup> Short-circuit to ground, one amplifier per package.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



## 5.4 Thermal Information: TLV387

|                       |  | TLV387       |      |
|-----------------------|--|--------------|------|
|                       | THERMAL METRIC <sup>(1)</sup>                | DBV (SOT-23) | UNIT |
|                       |  | 5 PINS       |      |
| R <sub>0JA</sub>      | Junction-to-ambient thermal resistance       | 187.1        | °C/W |
| R <sub>θJC(top)</sub> | Junction-to-case(top) thermal resistance     | 107.4        | °C/W |
| $R_{\theta JB}$       | Junction-to-board thermal resistance         | 57.5         | °C/W |
| $\Psi_{JT}$           | Junction-to-top characterization parameter   | 33.5         | °C/W |
| $\Psi_{JB}$           | Junction-to-board characterization parameter | 57.1         | °C/W |
| R <sub>θJC(bot)</sub> | Junction-to-case(bottom) thermal resistance  | N/A          | °C/W |

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

## 5.5 Thermal Information: TLV2387

|                       |  | TLV      | TLV2387     |      |  |
|-----------------------|--|----------|-------------|------|--|
|                       | THERMAL METRIC <sup>(1)</sup>                | D (SOIC) | DGK (VSSOP) | UNIT |  |
|                       |  | 8 PINS   | 8 PINS      |      |  |
| $R_{\theta JA}$       | Junction-to-ambient thermal resistance       | 127.9    | 165         | °C/W |  |
| R <sub>0JC(top)</sub> | Junction-to-case (top) thermal resistance    | 69.9     | 53          | °C/W |  |
| $R_{\theta JB}$       | Junction-to-board thermal resistance         | 71.4     | 87          | °C/W |  |
| $\Psi_{JT}$           | Junction-to-top characterization parameter   | 21.5     | 4.9         | °C/W |  |
| $\Psi_{JB}$           | Junction-to-board characterization parameter | 70.7     | 85          | °C/W |  |
| R <sub>0JC(bot)</sub> | Junction-to-case (bottom) thermal resistance | N/A      | N/A         | °C/W |  |

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

## 5.6 Thermal Information: TLV4387

|                       |  | TLV4387    |      |
|-----------------------|--|------------|------|
|                       | THERMAL METRIC(1)                            | PW (TSSOP) | UNIT |
|                       |  | 14 PINS    |      |
| $R_{\theta JA}$       | Junction-to-ambient thermal resistance       | 109.6      | °C/W |
| R <sub>0JC(top)</sub> | Junction-to-case (top) thermal resistance    | 27.4       | °C/W |
| R <sub>0JB</sub>      | Junction-to-board thermal resistance         | 56.1       | °C/W |
| $\Psi_{JT}$           | Junction-to-top characterization parameter   | 1.5        | °C/W |
| $\Psi_{JB}$           | Junction-to-board characterization parameter | 54.9       | °C/W |
| $R_{\theta JC(bot)}$  | Junction-to-case (bottom) thermal resistance | N/A        | °C/W |

 For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

Product Folder Links: TLV387 TLV2387 TLV4387



# **5.7 Electrical Characteristics**

at  $T_A$  = 25°C,  $R_L$  = 10 k $\Omega$  connected to  $V_S$  / 2,  $V_S$  = 1.7 V to 5.5 V,  $V_{CM}$  =  $V_S$  / 2,  $V_{OUT}$  =  $V_S$  / 2, and min and max specification established from manufacturing final test (unless otherwise noted)

| Input offset voltage Input offset voltage drift Power supply rejection ratio | $V_S = 5.5 \text{ V}$ $V_S = 1.7 \text{ V}$ $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(1)}$ |  |  | ±1                   | ±5   |  |  |
|--|--|--|--|----------------------|--|--|--|
| Input offset voltage drift Power supply rejection ratio                      | $V_S = 1.7 \text{ V}$ $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(1)}$                       |  |  |                      | ±5   |  |  |
| Input offset voltage drift Power supply rejection ratio                      | $T_A = -40$ °C to +125°C <sup>(1)</sup>  |  |  | -                    |  |  |  |
| Power supply rejection ratio   |  |  |  | ±1.25                | ±6   | μV   |  |
| ratio  | T = 40°C to :405°C(1)  |  |  | ±0.01                | ±0.05  | μV/°C  |  |
|  | T = 40°C to :400°C(1)  |  |  | ±0.05                | ±0.5   |  |  |
| CURRENT  | $_{\rm A} = -40^{\circ} \rm C \ to \ +125^{\circ} C^{(1)}$   |  |  |                      | ±1   | μV/V   |  |
|  |  |  |  |                      | '  |  |  |
| land biograms  |  |  |  | ±60                  | ±300   | ^  |  |
| input bias current   | $T_A = -40$ °C to +125°C <sup>(1)</sup>  |  |  |                      | ±350   | рA   |  |
| Input offset current   |  |  |  | ±60                  | ±500   | nΛ   |  |
| input onset current  | $T_A = -40$ °C to +125°C <sup>(1)</sup>  |  |  |                      | ±700   | рA   |  |
|  |  |  |  |                      |  |  |  |
| Input voltage poice  | f = 0.1 Hz to 10 Hz  |  |  | 177                  |  | $nV_PP$  |  |
| input voltage noise  | 1 - 0.1 HZ tO 10 HZ  |  |  | 27                   |  | nV <sub>RMS</sub>                                      |  |
|  | f = 1 Hz   |  |  | 8.5                  |  |  |  |
| Input voltago poiso donsity  | f = 10 Hz  |  |  | 8.5                  |  | nV/√ <del>Hz</del>                                     |  |
| input voltage noise density  | f = 100 Hz   |  |  | 8.5                  |  |  |  |
|  | f = 1 kHz  |  |  | 8.5                  |  |  |  |
| Input current noise  | f = 1 kHz  |  |  | 70                   |  | fA/√ <del>Hz</del>                                     |  |
| AGE .  |  |  |  |                      |  |  |  |
| Common-mode voltage  | V <sub>S</sub> = 1.7 V   |  | (V-) - 0.1   |                      | (V+)   | V  |  |
| range  | V <sub>S</sub> = 5.5 V   |  | (V-) - 0.2   |                      | (V+) + 0.1   | V  |  |
|  | $(V-) - 0.1 V < V_{CM} < (V+), V_{CM}$   | V <sub>S</sub> = 1.7 V   | 115  | 138                  |  |  |  |
| Common mode rejection  | $(V-) - 0.2 V < V_{CM} < (V+) +$   | - 0.1 V, V <sub>S</sub> = 5.5 V  | 130  | 150                  |  |  |  |
| ratio  | $(V-) - 0.1 V < V_{CM} < (V+),$  | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(1)}$   | 110  | 132                  |  | dB   |  |
|  | $(V-) - 0.2 V < V_{CM} < (V+) + T_A = -40$ °C to +125°C <sup>(1)</sup>                                 | $-0.1$ , $V_S = 5.5 V$ ,   | 130  |                      |  |  |  |
| CITANCE  |  |  |  |                      |  |  |  |
| Differential   |  |  |  | 100    3             |  | MΩ    pF   |  |
| Common-mode  |  |  |  | 60    3              |  | GΩ    pF   |  |
| GAIN   |  |  |  |                      |  |  |  |
|  | (V–) + 100 mV < V <sub>OUT</sub> <   |  | 120  | 145                  |  |  |  |
|  | (V+) – 100 mV  | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(1)}$   | 115  |                      |  | 1  |  |
| Open-loop voltage gain   | (V–) + 150 mV < V <sub>OUT</sub> <   |  | 120  | 145                  |  | dB   |  |
|  |  | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(1)}$   | 115  |                      |  |  |  |
|  | Common-mode voltage range  Common-mode rejection ratio  CITANCE  Differential  Common-mode             | Input offset current $T_{A} = -40^{\circ}\text{C to} + 125^{\circ}\text{C}^{(1)}$ $T_{A} = -40^{\circ}\text{C to} + 125^{\circ}\text{C}^{(1)}$ Input voltage noise $f = 0.1 \text{ Hz to } 10 \text{ Hz}$ $f = 1 \text{ Hz}$ $f = 10 \text{ Hz}$ $f = 10 \text{ Hz}$ $f = 10 \text{ Hz}$ $f = 1 \text{ kHz}$ Input current noise $f = 1 \text{ kHz}$ $GE$ Common-mode voltage range $V_{S} = 1.7 \text{ V}$ $V_{S} = 5.5 \text{ V}$ $(V-) - 0.1 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-) - 0.2 \text{ V} < V_{CM} < (V+),$ $(V-)$ | Input offset current $T_{A} = -40^{\circ}\text{C to } + 125^{\circ}\text{C}^{(1)}$ $T_{A} = -40^{\circ}\text{C to } + 125^{\circ}\text{C}^{(1)}$ Input voltage noise $f = 0.1 \text{ Hz to } 10 \text{ Hz}$ $f = 1 \text{ Hz}$ $f = 10 \text{ Hz}$ $f = 10 \text{ Hz}$ $f = 10 \text{ Hz}$ $f = 1 \text{ kHz}$ Input current noise $f = 1 \text{ kHz}$ $ge$ Common-mode voltage range $V_{S} = 1.7 \text{ V}$ $V_{S} = 5.5 \text{ V}$ $(V_{-}) - 0.1 \text{ V} < V_{CM} < (V_{+}), V_{S} = 1.7 \text{ V}$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1 \text{ V}, V_{S} = 5.5 \text{ V}$ $(V_{-}) - 0.1 \text{ V} < V_{CM} < (V_{+}) + 0.1 \text{ V}, V_{S} = 5.5 \text{ V}$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) - 0.2 \text{ V} < V_{CM} < (V_{+}) + 0.1, V_{S} = 5.5 \text{ V},$ $(V_{-}) + 100 \text{ mV} < V_{OM} < V_{OM}$ | Input offset current | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ |  |

# 5.7 Electrical Characteristics (continued)

at  $T_A$  = 25°C,  $R_L$  = 10 k $\Omega$  connected to  $V_S$  / 2,  $V_S$  = 1.7 V to 5.5 V,  $V_{CM}$  =  $V_S$  / 2,  $V_{OUT}$  =  $V_S$  / 2, and min and max specification established from manufacturing final test (unless otherwise noted)

|                 | PARAMETER                               | TEST   | MIN   | TYP          | MAX          | UNIT        |         |
|-----------------|---|--|---|--------------|--------------|-------------|---------|
| FREQUEN         | CY RESPONSE                             |  |   |              |              |             |         |
| GBW             | Gain-bandwidth product                  |  |   |              | 5.7          |             | MHz     |
| SR              | Slew rate                               | 4-V step, G = +1   |   |              | 2.8          |             | V/µs    |
| t <sub>S</sub>  | 0                                       | To 0.1%, 1-V step, G = +                                       | +1  |              | 1.5          |             | μs      |
|                 | Settling time                           | To 0.01%, 1-V step, G =  | +1  |              | 2.5          |             |         |
|                 | Overload recovery time                  | V <sub>IN</sub> × G > V <sub>S</sub>                           |   |              | 500          |             | ns      |
|                 | Chopping clock frequency <sup>(1)</sup> |  |   | 100          | 150          |             | kHz     |
| THD+N           | Total harmonic distortion + noise       | V <sub>OUT</sub> = 1 V <sub>RMS</sub> , G = +1,                | f = 1 kHz, R <sub>L</sub> = 10 kΩ                   |              | 0.002 %      |             |         |
| OUTPUT          |   |  |   |              |              |             |         |
|                 |   | no load  |   |              | 1            | 20          |         |
|                 | Voltage output swing from               |  |   | 5            | 30           | mV          |         |
|                 | rail                                    | R <sub>L</sub> = 2 kΩ  |   | 20           | 75           |             |         |
|                 |   | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(1)}$     |   |              |              | 30          |         |
|                 | High linearity output swing             | A > 400 dD   |   | (V-) + 0.075 | (\           | '+) - 0.075 |         |
|                 | range <sup>(1)</sup>                    | A <sub>OL</sub> > 120 dB                                       | $R_L = 2 k\Omega$                                   | (V-) + 0.150 | (V+) - 0.150 |             | V       |
|                 | Ob and allowed account                  | V <sub>S</sub> = 5.5 V   | ±55   |              |              | ^           |         |
| I <sub>SC</sub> | Short-circuit current                   | V <sub>S</sub> = 1.7 V   |   | ±15          |              | - mA        |         |
|                 | Phase margin                            | C <sub>L</sub> = 100 pF, G = +1                                |   |              | 40           |             | degrees |
| POWER S         | UPPLY                                   | •  |   |              | ,            | '           |         |
| IQ              | Quiescent current per                   | L = 0 A  |   |              | 570          | 675         | μA      |
|                 | amplifier                               | I <sub>O</sub> = 0 mA  | $T_A = -40^{\circ}C \text{ to } 125^{\circ}C^{(1)}$ |              |              | 700         | μA      |
|                 | Turn-on time                            | V <sub>S</sub> = 5.5 V,<br>V <sub>S</sub> ramp rate > 0.3 V/μs |   | 25           | 100          | μs          |         |

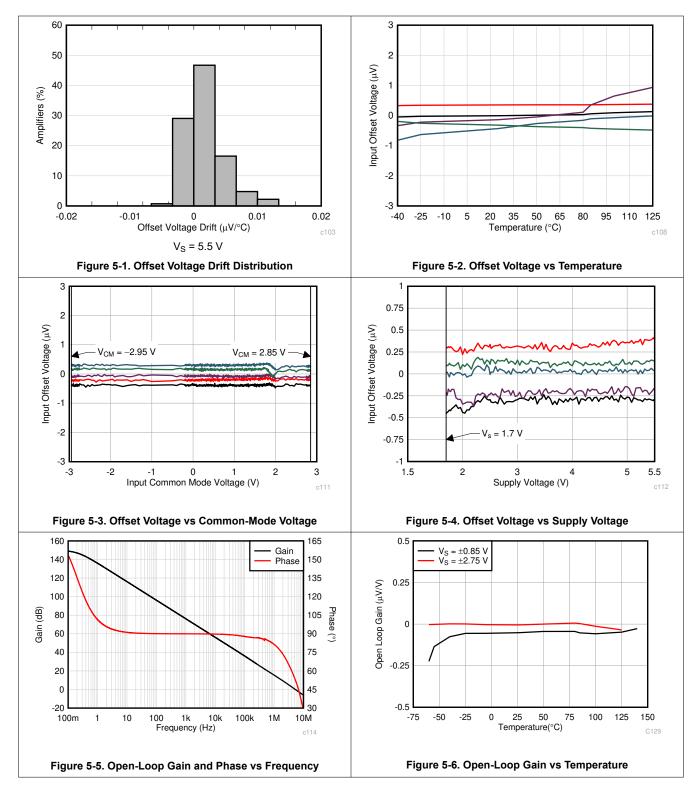
<sup>(1)</sup> Specification established from device population bench system measurements across multiple lots.

Product Folder Links: TLV387 TLV2387 TLV4387



## 5.8 Typical Characteristics

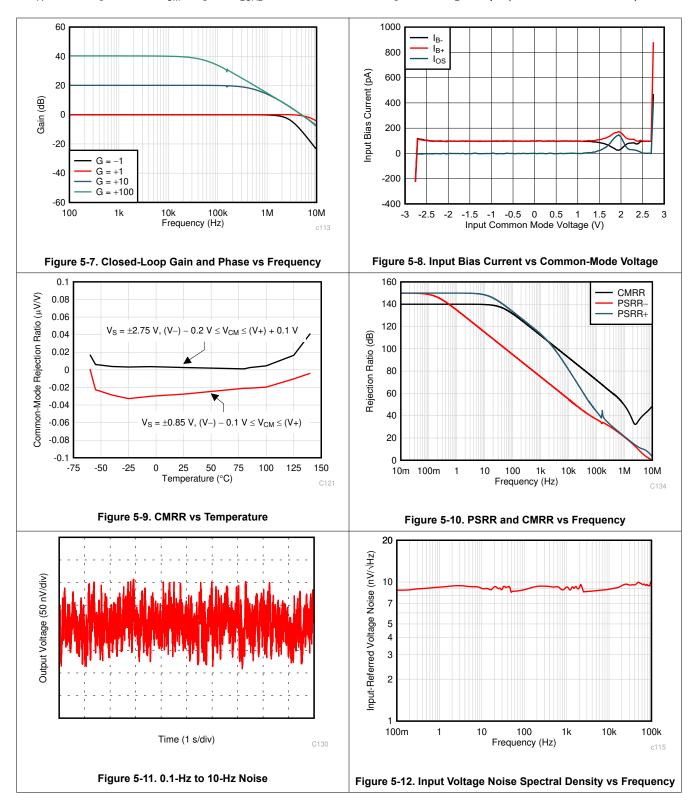
at  $T_A$  = 25°C,  $V_S$  = ±2.5 V,  $V_{CM}$  =  $V_S$  / 2,  $R_{LOAD}$  = 10 k $\Omega$  connected to  $V_S$  / 2, and  $C_L$  = 50 pF (unless otherwise noted)





## **5.8 Typical Characteristics (continued)**

at  $T_A$  = 25°C,  $V_S$  = ±2.5 V,  $V_{CM}$  =  $V_S$  / 2,  $R_{LOAD}$  = 10 k $\Omega$  connected to  $V_S$  / 2, and  $C_L$  = 50 pF (unless otherwise noted)



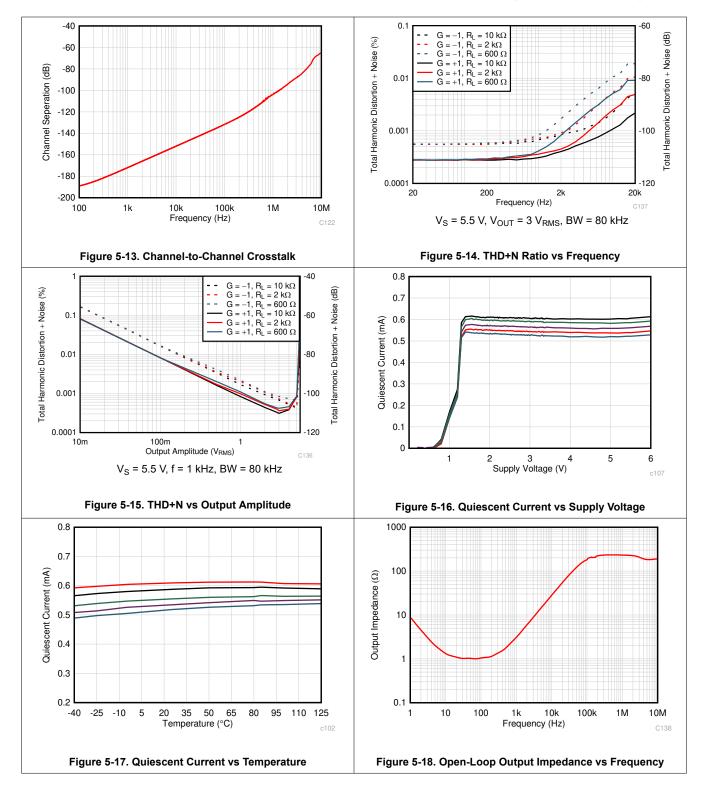
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# **5.8 Typical Characteristics (continued)**

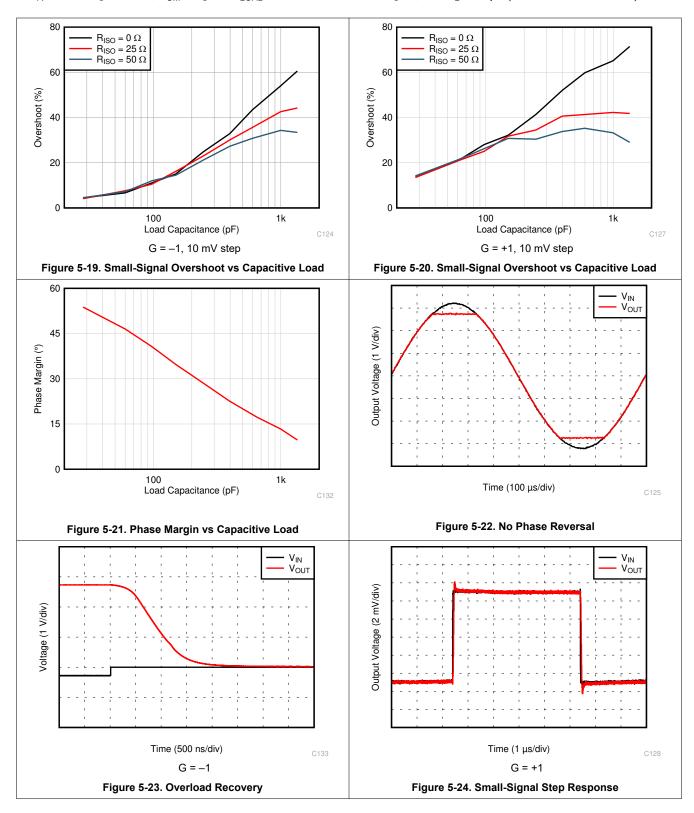
at  $T_A$  = 25°C,  $V_S$  = ±2.5 V,  $V_{CM}$  =  $V_S$  / 2,  $R_{LOAD}$  = 10 k $\Omega$  connected to  $V_S$  / 2, and  $C_L$  = 50 pF (unless otherwise noted)





# **5.8 Typical Characteristics (continued)**

at  $T_A$  = 25°C,  $V_S$  = ±2.5 V,  $V_{CM}$  =  $V_S$  / 2,  $R_{LOAD}$  = 10 k $\Omega$  connected to  $V_S$  / 2, and  $C_L$  = 50 pF (unless otherwise noted)



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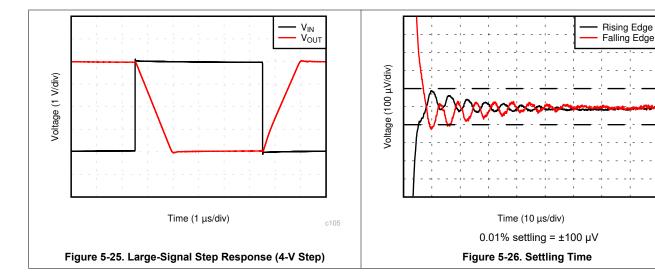
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# **5.8 Typical Characteristics (continued)**

at  $T_A = 25$ °C,  $V_S = \pm 2.5$  V,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10$  k $\Omega$  connected to  $V_S / 2$ , and  $C_L = 50$  pF (unless otherwise noted)

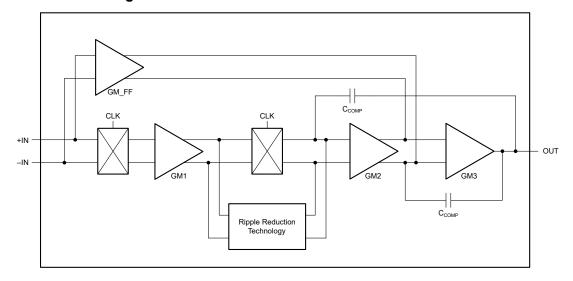


# **6 Detailed Description**

## 6.1 Overview

The TLVx387 family of zero-drift amplifiers is engineered with state-of-the-art, proprietary, precision zero-drift technology. These amplifiers offer ultra-low input offset voltage and drift, and achieve excellent input and output dynamic linearity. The TLVx387 operate from 1.7 V to 5.5 V, are unity-gain stable, and are designed for a wide range of general-purpose and precision applications. The TLVx387 strengths also include a 5.7-MHz bandwidth, 8.5-nV/\hdot Hz noise spectral density, and no 1/f noise, making the TLVx387 an excellent choice for interfacing with sensor modules, and buffering high-fidelity, digital-to-analog converters (DACs).

# 6.2 Functional Block Diagram



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## **6.3 Feature Description**

## 6.3.1 Input Bias Current

During normal operation, the typical input bias current of the TLVx387 is 30 pA. The device exhibits low drift over the full temperature range of –40°C to +125°C. There are no antiparallel diodes between the input pins (+IN and –IN); therefore, the differential input maximum voltage is limited only by diodes connected to the supply voltage pins. However, use caution in cases where the input differential voltage exceeds the nominal operating input differential voltage. When inputs are separated, the switching offset-cancellation path internal to the amplifier exceeds normal operating conditions, and can potentially create long settling behavior upon return to normal operation. The equivalent input circuit of TLVx387 is shown in Figure 6-1.

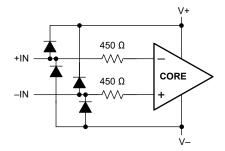


Figure 6-1. Equivalent Input Circuit

#### 6.3.2 EMI Susceptibility and Input Filtering

Operational amplifiers can exhibit sensitivity to electromagnetic interference (EMI). Typically, conducted EMI (that is, EMI that enters the device through conduction) is more commonly observed than radiated EMI (that is, EMI that enters the device through radiation). When conducted EMI enters the operational amplifier, the dc offset at the amplifier output can shift from the nominal value. This shift is a result of signal rectification associated with the internal semiconductor junctions. Although all operational amplifier pin functions can be affected by EMI, the input pins are likely to be the most susceptible. The TLVx387 operational amplifier family incorporates an internal input low-pass filter that reduces the amplifier response to EMI. Both common-mode and differential-mode filtering are provided by the input filter. The conducted EMI rejection of the TLVx387 is seen in Figure 6-2.

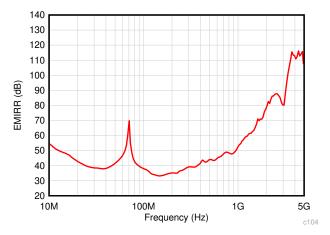


Figure 6-2. EMI Rejection Ratio

## **6.4 Device Functional Modes**

The TLVx387 have a single functional mode and are operational when the power-supply voltage is greater than 1.7 V ( $\pm 0.85$  V). The maximum specified power-supply voltage for the TLVx387 is 5.5 V ( $\pm 2.75$  V).

# 7 Application and Implementation

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 7.1 Application Information

The TLVx387 are unity-gain stable, precision, operational amplifiers featuring state-of-the-art, zero-drift technology. The use of proprietary zero-drift circuitry gives the benefit of low input offset voltage over time and temperature, as well as lower 1/f noise component. As a result of the high PSRR, the devices work well in applications that run directly from battery power without regulation. The TLVx387 family is optimized for full rail-to-rail input, allowing for low-voltage, single-supply operation or split-supply use. These miniature, high-precision, low-noise amplifiers offer high-impedance inputs that have a common-mode range 100 mV beyond the supplies without input crossover distortion, and a rail-to-rail output that swings within 5 mV of the supplies under normal test conditions. The TLVx387 precision amplifiers are designed for upstream analog signal-chain applications in low or high gains, as well as downstream signal-chain functions, such as DAC buffering.

## 7.1.1 Zero-Drift Clocking

The TLVx387 use an advanced zero-drift architecture to achieve ultra-low offset and offset drift. This architecture uses a clock and switches internally to create a dc error-correction path. The clocking is filtered internally, and typically not observable for most configurations. Take the following precautions to minimize clock noise in the signal chain. The clocking creates a small charge-injection pulse at the input of the amplifier; therefore, do not use high-value resistors (> 100 k $\Omega$ ) in series with the inputs to avoid higher clock voltage noise at the output. The charge injection pulses are minimized when the impedance to the input pins is matched. If higher value resistors are used, then use matching impedances on both amplifier input pins.

## 7.2 Typical Applications

#### 7.2.1 Bidirectional Current Sensing

This single-supply, low-side, bidirectional current-sensing design example detects load currents from -1 A to +1 A. The single-ended output spans from 110 mV to 3.19 V. This design uses the TLVx387 because of the device low offset voltage and rail-to-rail input and output. One of the amplifiers is configured as a difference amplifier and the other amplifier provides the reference voltage. Figure 7-1 shows the design example schematic.

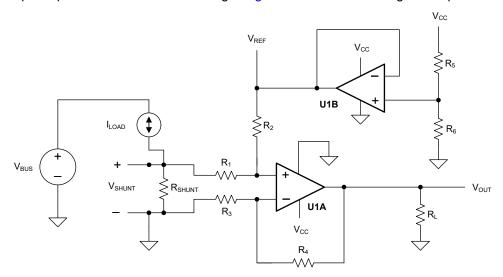


Figure 7-1. Bidirectional Current-Sensing Schematic

Product Folder Links: TLV387 TLV2387 TLV4387

#### 7.2.1.1 Design Requirements

This design example has the following requirements:

Supply voltage: 3.3 VInput: -1 A to +1 A

Output: 1.65 V ±1.54 V (110 mV to 3.19 V)

#### 7.2.1.2 Detailed Design Procedure

The load current,  $I_{LOAD}$ , flows through the shunt resistor,  $R_{SHUNT}$ , to develop the shunt voltage,  $V_{SHUNT}$ . The shunt voltage is then amplified by the difference amplifier consisting of U1A and  $R_1$  through  $R_4$ . The gain of the difference amplifier is set by the ratio of  $R_4$  to  $R_3$ . To minimize errors, set  $R_2 = R_4$  and  $R_1 = R_3$ . The reference voltage,  $V_{REF}$ , is supplied by buffering a resistor divider using U1B. The transfer function is given by Equation 1.

$$V_{OUT} = V_{SHUNT} \times Gain_{Diff\_Amp} + V_{REF}$$
 (1)

where

• 
$$V_{SHUNT} = I_{LOAD} \times R_{SHUNT}$$

Gain<sub>Diff\_Amp</sub> = 
$$\frac{R_4}{R_3}$$

$$V_{REF} = V_{CC} \times \left[ \frac{R_6}{R_5 + R_6} \right]$$

There are two types of errors in this design: gain and offset. Gain errors are introduced by the tolerance of the shunt resistor and the ratios of  $R_4$  to  $R_3$  and, similarly,  $R_2$  to  $R_1$ . Offset errors are introduced by the voltage divider ( $R_5$  and  $R_6$ ) and how closely the ratio of  $R_4$  /  $R_3$  matches  $R_2$  /  $R_1$ . The latter value affects the CMRR of the difference amplifier, ultimately translating to an offset error.

The value of  $V_{SHUNT}$  is the ground potential for the system load because  $V_{SHUNT}$  is a low-side measurement. Therefore, a maximum value must be placed on  $V_{SHUNT}$ . In this design, the maximum value for  $V_{SHUNT}$  is set to 100 mV. Equation 2 calculates the maximum value of the shunt resistor given a maximum shunt voltage of 100 mV and maximum load current of 1 A.

$$R_{SHUNT(Max)} = \frac{V_{SHUNT(Max)}}{I_{LOAD(Max)}} = \frac{100 \text{ mV}}{1 \text{ A}} = 100 \text{ m}\Omega$$
(2)

The tolerance of R<sub>SHUNT</sub> is directly proportional to cost. For this design, a shunt resistor with a tolerance of 0.5% is selected. If greater accuracy is required, select a 0.1% resistor or better.

The load current is bidirectional; therefore, the shunt voltage range is -100 mV to +100 mV. This voltage is divided down by  $R_1$  and  $R_2$  before reaching the operational amplifier, U1A. Make sure that the voltage present at the noninverting node of U1A is within the common-mode range of the device. Use an operational amplifier, such as the TLVx387, that has a common-mode range that extends below the negative supply voltage. The offset error is minimal because the TLVx387 has a typical offset voltage of merely  $\pm 0.25 \ \mu V$  ( $\pm 5 \ \mu V$ , maximum).

Given a symmetric load current of -1 A to +1 A, the voltage divider resistors,  $R_5$  and  $R_6$ , must be equal. To be consistent with the shunt resistor, a tolerance of 0.5% is selected. To minimize power consumption,  $10-k\Omega$  resistors are used.

To set the gain of the difference amplifier, the common-mode range and output swing of the TLVx387 must be considered. Equation 3 and Equation 4 depict the typical common-mode range and maximum output swing, respectively, of the TLVx387 given a 3.3-V supply.

$$-100 \text{ mV} < V_{CM} < 3.4 \text{ V}$$
 (3)

$$100 \text{ mV} < V_{\text{OUT}} < 3.2 \text{ V}$$
 (4)



The gain of the difference amplifier can now be calculated as shown in Equation 5.

$$Gain_{Diff\_Amp} = \frac{V_{OUT\_Max} - V_{OUT\_Min}}{R_{SHUNT} \times (I_{MAX} - I_{MIN})} = \frac{3.2 \text{ V} - 100 \text{ mV}}{100 \text{ m}\Omega \times [1 \text{ A} - (-1 \text{A})]} = 15.5 \frac{\text{V}}{\text{V}}$$
(5)

The resistor value selected for  $R_1$  and  $R_3$  is 1 k $\Omega$ . 15.4 k $\Omega$  is selected for  $R_2$  and  $R_4$  because this number is the nearest standard value. Therefore, in this example, the calculated gain of the difference amplifier is 15.4 V/V.

The gain error of the circuit primarily depends on  $R_1$  through  $R_4$ . As a result of this dependence, 0.1% resistors were selected. This configuration reduces the likelihood that the design requires a two-point calibration. A simple one-point calibration, if desired, removes the offset errors introduced by the 0.5% resistors.

#### 7.2.1.3 Application Curve

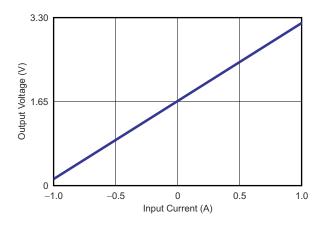


Figure 7-2. Bidirectional Current-Sensing Circuit Performance: Output Voltage vs Input Current

#### 7.2.2 Load Cell Measurement

Figure 7-3 shows the TLVx387 in a high-CMRR dual-op amp instrumentation amplifier with a trim resistor and six-wire load cell for precision measurement.

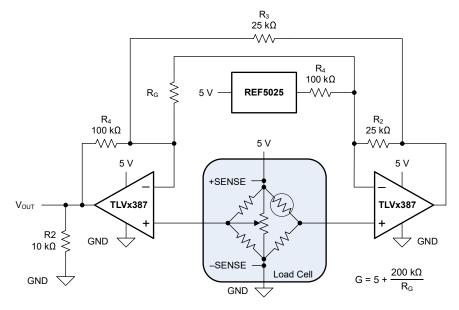


Figure 7-3. Load Cell Measurement Schematic

Product Folder Links: TLV387 TLV2387 TLV4387

## 7.3 Power Supply Recommendations

The TLVx387 family of devices is specified for operation from 1.7 V to 5.5 V for single supplies, and  $\pm 0.85$  V to  $\pm 2.75$  V for dual supplies. Key parameters that can exhibit significant variance with regard to operating voltage are presented in Section 5.8.

#### **CAUTION**

Supply voltages greater than 6 V can permanently damage the device (see Section 5.1).

#### 7.4 Layout

## 7.4.1 Layout Guidelines

Pay attention to good layout practice. Keep traces short and, when possible, use a printed-circuit board (PCB) ground plane with surface-mount components placed as close to the device pins as possible. Place a 0.1-µF capacitor close to the supply pins. These guidelines must be applied throughout the analog circuit to improve performance, and provide benefits such as reducing the electromagnetic interference (EMI) susceptibility.

For lowest offset voltage and precision performance, optimize circuit layout and mechanical conditions. Avoid temperature gradients that create thermoelectric (Seebeck) effects in the thermocouple junctions formed from connecting dissimilar conductors. Cancel these thermally-generated potentials by making sure that the potentials are equal on both input pins. Other layout and design considerations include:

- Use low thermoelectric-coefficient conditions (avoid dissimilar metals).
- Thermally isolate components from power supplies or other heat sources.
- · Shield operational amplifier and input circuitry from air currents, such as cooling fans.

Follow these guidelines to reduce the likelihood of junctions being at different temperatures, which can cause thermoelectric voltage drift of  $0.1~\mu\text{V}/^{\circ}\text{C}$  or higher depending on materials used.

### 7.4.2 Layout Example

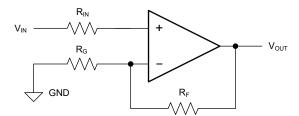


Figure 7-4. Schematic Representation

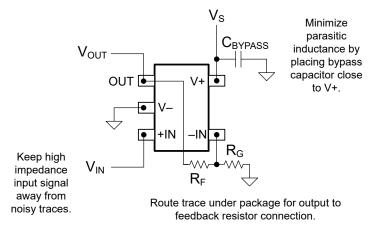


Figure 7-5. Layout Example

# 8 Device and Documentation Support

# 8.1 Device Support

# 8.1.1 Development Support

## 8.1.1.1 PSpice® for TI

PSpice® for TI is a design and simulation environment that helps evaluate performance of analog circuits. Create subsystem designs and prototype solutions before committing to layout and fabrication, reducing development cost and time to market.

## 8.1.1.2 TINA-TI™ Simulation Software (Free Download)

TINA-TI™ simulation software is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI simulation software is a free, fully-functional version of the TINA™ software, preloaded with a library of macromodels, in addition to a range of both passive and active models. TINA-TI simulation software provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Design tools and simulation web page, TINA-TI simulation software offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

#### Note

These files require that either the TINA software or TINA-TI software be installed. Download the free TINA-TI simulation software from the TINA-TI™ software folder.

## **8.2 Documentation Support**

#### 8.2.1 Related Documentation

For related documentation see the following: Texas Instruments, Circuit board layout techniques

### 8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 8.4 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 8.5 Trademarks

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TINA<sup>™</sup> is a trademark of DesignSoft, Inc.

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# 8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



## 8.7 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

# 9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| С | hanges from Revision A (November 2023) to Revision B (December 2023)                              | Page |
|---|---|------|
|   | hanged document status from production mix to production data                                     |      |
| C | changes from Revision * (December 2021) to Revision A (November 2023)                             | Page |
|   |   |      |
|   | Changed document status from production data to production mix with addition of preview D package | 1    |

# 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package   Pins   | Package qty   Carrier | RoHS | Lead finish/<br>Ball material | MSL rating/<br>Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|--------|---------------|------------------|-----------------------|------|-------------------------------|----------------------------|--------------|------------------|
|                       | (-)    | (=)           |                  |                       | (5)  | (4)                           | (5)                        |              | (-)              |
| TLV2387DGKR           | Active | Production    | VSSOP (DGK)   8  | 2500   LARGE T&R      | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | 3BBT             |
| TLV2387DGKR.A         | Active | Production    | VSSOP (DGK)   8  | 2500   LARGE T&R      | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | 3BBT             |
| TLV2387DR             | Active | Production    | SOIC (D)   8     | 3000   LARGE T&R      | Yes  | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | TL2387           |
| TLV2387DR.A           | Active | Production    | SOIC (D)   8     | 3000   LARGE T&R      | Yes  | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | TL2387           |
| TLV387DBVR            | Active | Production    | SOT-23 (DBV)   5 | 3000   LARGE T&R      | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | 2LOT             |
| TLV387DBVR.A          | Active | Production    | SOT-23 (DBV)   5 | 3000   LARGE T&R      | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | 2LOT             |
| TLV387DBVT            | Active | Production    | SOT-23 (DBV)   5 | 250   SMALL T&R       | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | 2LOT             |
| TLV387DBVT.A          | Active | Production    | SOT-23 (DBV)   5 | 250   SMALL T&R       | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | 2LOT             |
| TLV4387PWR            | Active | Production    | TSSOP (PW)   14  | 3000   LARGE T&R      | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | TLV4387          |
| TLV4387PWR.A          | Active | Production    | TSSOP (PW)   14  | 3000   LARGE T&R      | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | TLV4387          |

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



# PACKAGE OPTION ADDENDUM

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**PACKAGE MATERIALS INFORMATION** 

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## TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device      | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TLV2387DGKR | VSSOP           | DGK                | 8  | 2500 | 330.0                    | 12.4                     | 5.25       | 3.35       | 1.25       | 8.0        | 12.0      | Q1               |
| TLV2387DR   | SOIC            | D                  | 8  | 3000 | 330.0                    | 12.4                     | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TLV387DBVR  | SOT-23          | DBV                | 5  | 3000 | 178.0                    | 9.0                      | 3.3        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| TLV387DBVT  | SOT-23          | DBV                | 5  | 250  | 178.0                    | 9.0                      | 3.3        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| TLV4387PWR  | TSSOP           | PW                 | 14 | 3000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |



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#### \*All dimensions are nominal

| 7 till dillitoriolorio di o mominar |              |                 |      |      |             |            |             |
|-------------------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device                              | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
| TLV2387DGKR                         | VSSOP        | DGK             | 8    | 2500 | 366.0       | 364.0      | 50.0        |
| TLV2387DR                           | SOIC         | D               | 8    | 3000 | 353.0       | 353.0      | 32.0        |
| TLV387DBVR                          | SOT-23       | DBV             | 5    | 3000 | 190.0       | 190.0      | 30.0        |
| TLV387DBVT                          | SOT-23       | DBV             | 5    | 250  | 190.0       | 190.0      | 30.0        |
| TLV4387PWR                          | TSSOP        | PW              | 14   | 3000 | 353.0       | 353.0      | 32.0        |



SMALL OUTLINE INTEGRATED CIRCUIT



# NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE TRANSISTOR



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







### NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.





NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.





NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



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